

TOSHIBA THYRISITOR SILICON PLANAR TYPE

SF5G42,SF5J42

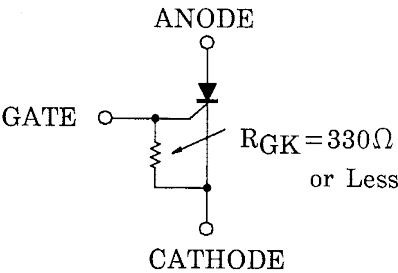
MEDIUM POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : $V_{DRM} = 400, 600V$
Repetitive Peak Reverse Voltage : $V_{RRM} = 400, 600V$
- Average On-State Current : $I_T(AV) = 5A$
- JEDEC TO-220AB Package.

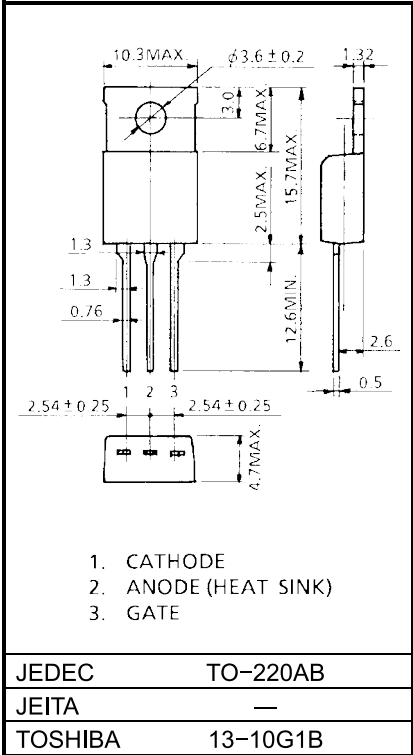
MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage (RGK = 330Ω)	SF5G42	V_{DRM} V_{RRM}	400	V
	SF5J42		600	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, $T_j = 0\sim125^{\circ}C$, RGK = 330Ω)	SF5G42	V_{RSM}	500	V
	SF5J42		720	
Average On-State Current (Half Sine Waveform $T_c = 91^{\circ}C$)		$I_T(AV)$	5	A
R.M.S On-State Current		$I_T(RMS)$	7.8	A
Peak One Cycle Surge On-State Current (Non-Repetitive)		I_{TSM}	80 (50Hz)	A
			88 (60Hz)	
I^2t Limit Value		I^2t	32	A^2s
Peak Gate Power Dissipation		P_{GM}	0.5	W
Average Gate Power Dissipation		$P_G(AV)$	0.05	W
Peak Forward Gate Voltage		V_{FGM}	5	V
Peak Reverse Gate Voltage		V_{RGM}	-5	V
Peak Forward Gate Current		I_{GM}	200	mA
Junction Temperature		T_j	-40~125	$^{\circ}C$
Storage Temperature Range		T_{stg}	-40~125	$^{\circ}C$

Note: Should be used with gate resistance as follows.



Unit: mm

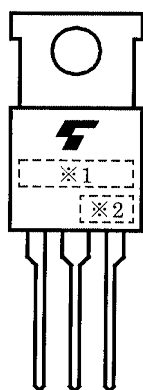


Weight: 2g

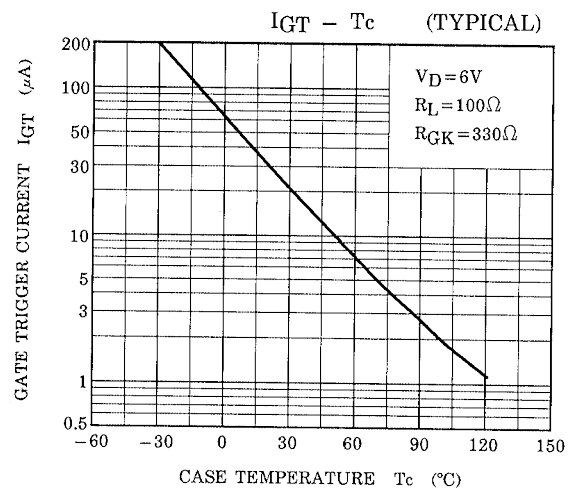
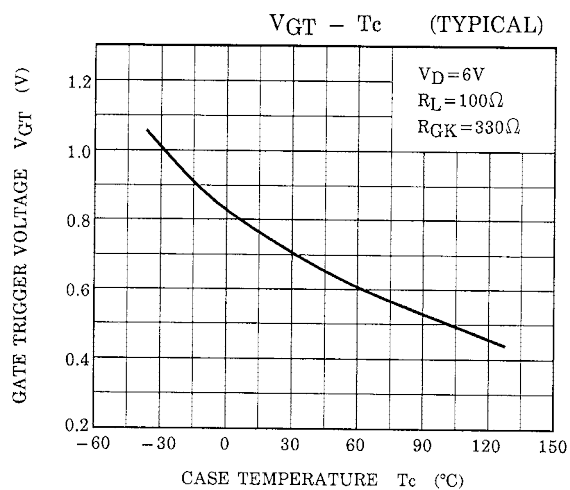
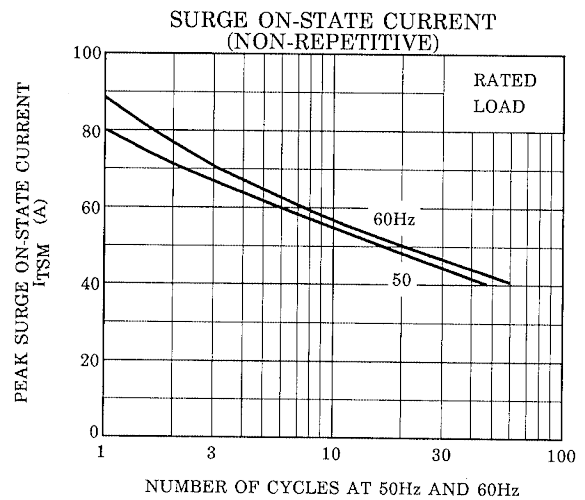
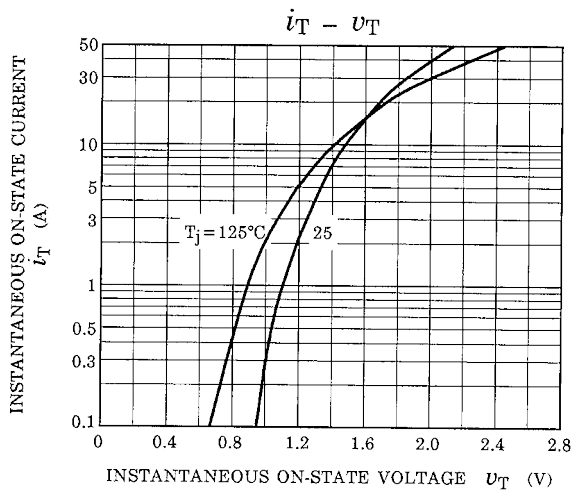
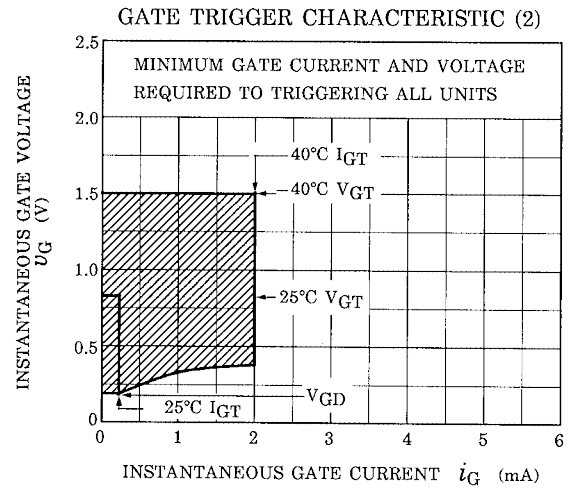
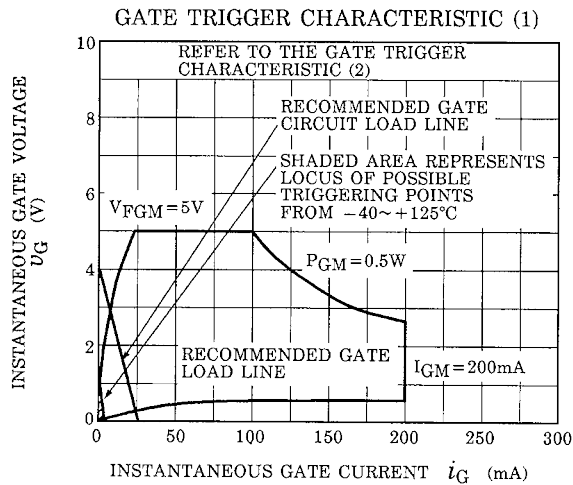
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

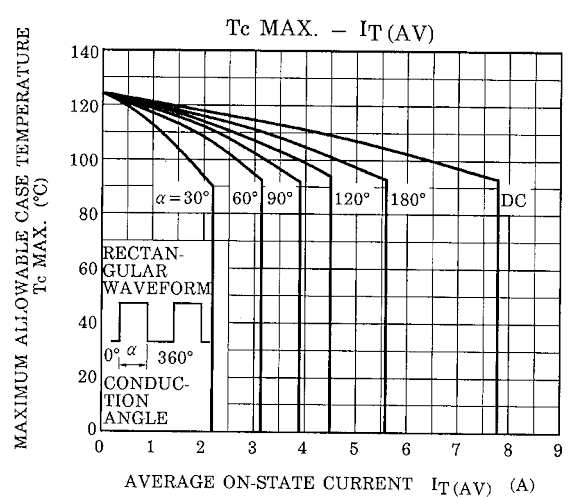
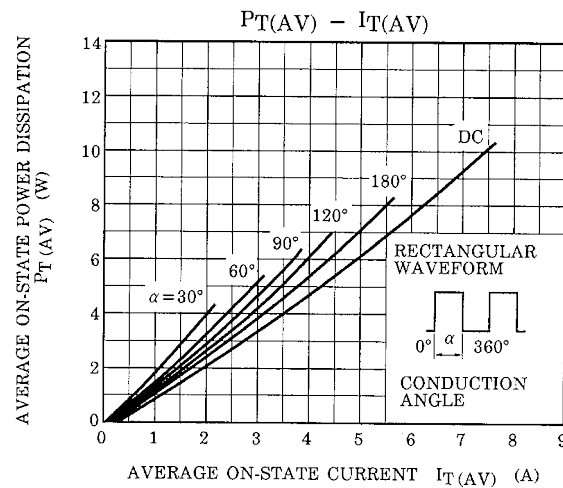
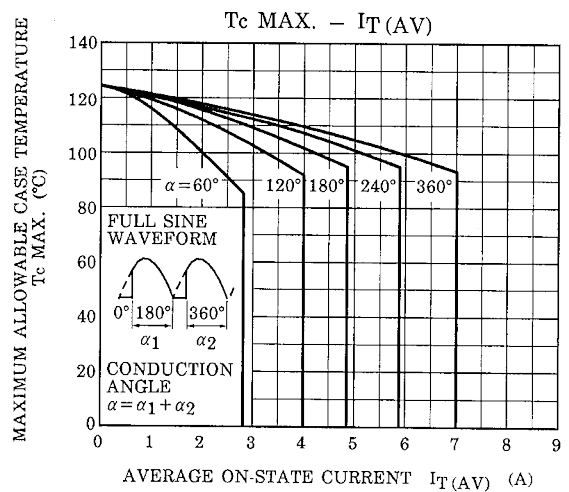
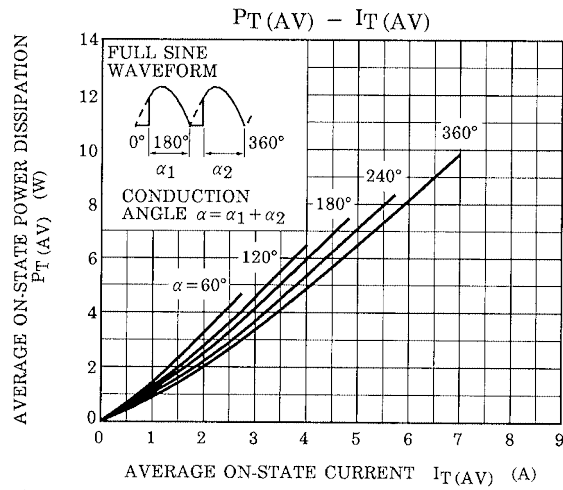
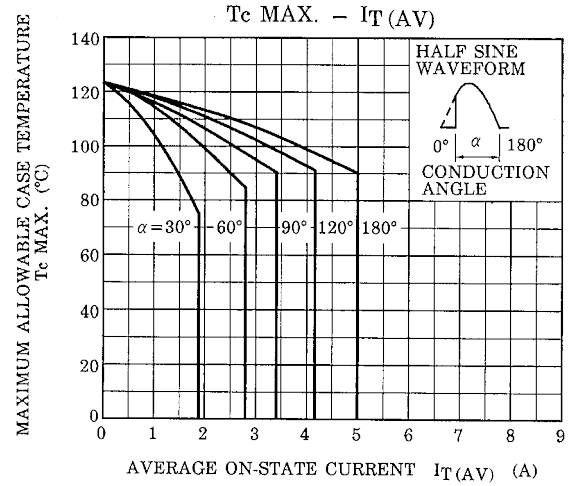
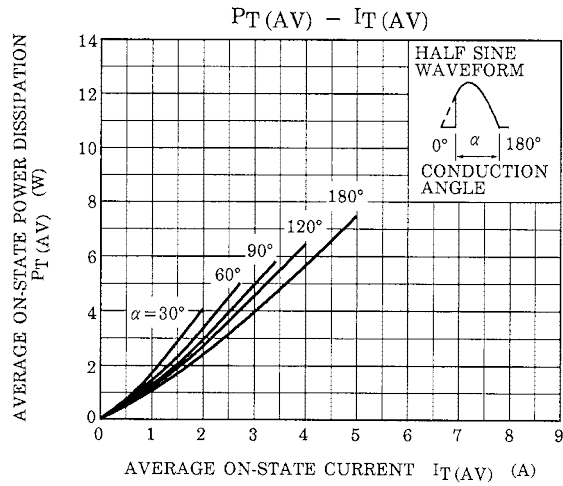
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM} = \text{Rated}$ $T_j = 125^\circ\text{C}$, $R_{GK} = 330\Omega$	—	—	2	mA
Peak On-State Voltage	V_{TM}	$I_{TM} = 15\text{A}$	—	—	1.6	V
Gate Trigger Voltage	V_{GT}	$V_D = 6\text{V}$, $R_L = 100\Omega$	—	—	0.8	V
Gate Trigger Current	I_{GT}	$R_{GK} = 330\Omega$	—	—	200	μA
Gate Non-Trigger Voltage	V_{GD}	$V_D = \text{Rated} \times 2 / 3$, $T_c = 125^\circ\text{C}$	0.2	—	—	V
Critical Rate of Rise of Off-State Voltage	dv / dt	$V_{DRM} = \text{Rated} \times 2 / 3$, $T_c = 75^\circ\text{C}$ $R_{GK} = 330\Omega$, Exponential Rise	—	50	—	$\text{V} / \mu\text{s}$
Holding Current	I_H	$R_L = 100\Omega$, $R_{GK} = 330\Omega$	—	4	—	mA
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	—	—	3	$^\circ\text{C} / \text{W}$

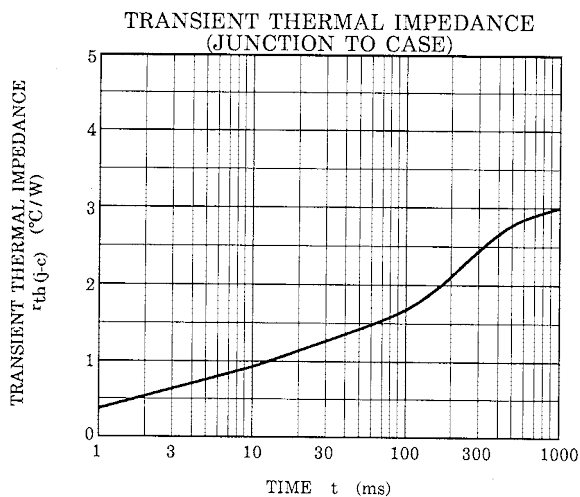
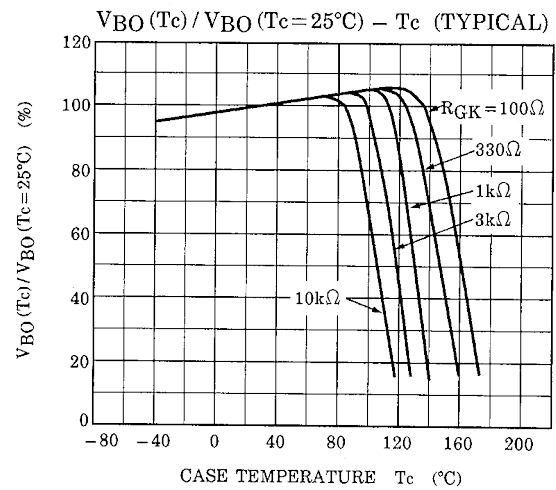
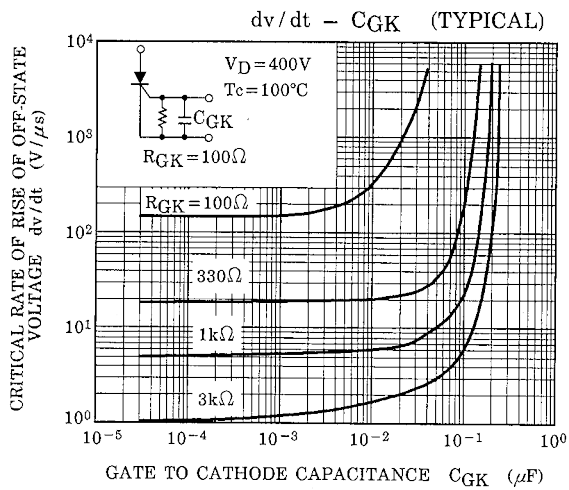
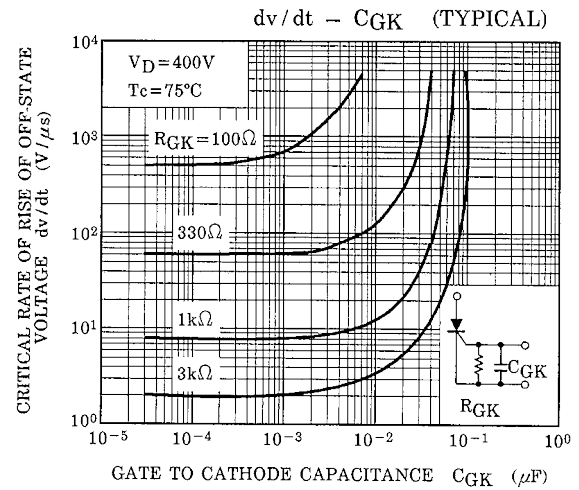
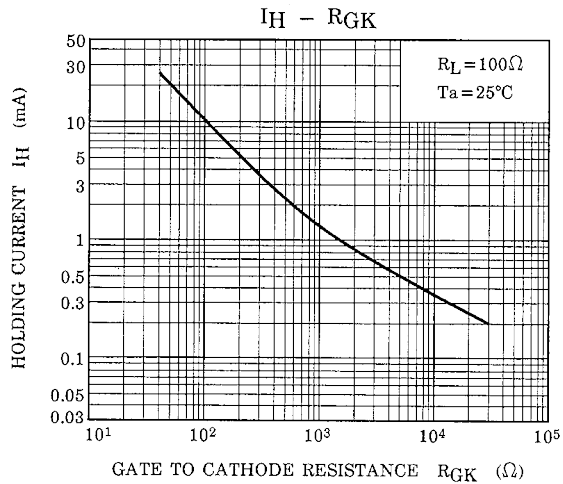
MARKING



NUMBER	SYMBOL		MARK
*1	TYPE	SF5G42	SF5G42
		SF5J42	SF5J42
*2	Lot Number <div style="display: flex; align-items: center;"> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> <div style="border: 1px solid black; width: 20px; height: 20px; margin-right: 5px;"></div> <div style="margin-left: 10px;"> Month (Starting from Alphabet A) </div> </div> <div style="margin-left: 10px;"> Year (Last Decimal Digit of the Current Year) </div>		Example 8A : January 1998 8B : February 1998 8L : December 1998







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